

# SPICE Device Model SUD50N06-08H

### **Vishay Siliconix**

### N-Channel 60-V (D-S) 175°C MOSFET

#### **CHARACTERISTICS**

- N-Channel Vertical DMOS
- · Macro Model (Subcircuit Model)
- Level 3 MOS

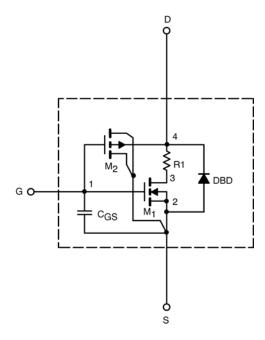
- Apply for both Linear and Switching Application
- Accurate over the -55 to 125°C Temperature Range
- Model the Gate Charge, Transient, and Diode Reverse Recovery Characteristics

#### **DESCRIPTION**

The attached spice model describes the typical electrical characteristics of the n-channel vertical DMOS. The subcircuit model is extracted and optimized over the -55 to  $125^{\circ}$ C temperature ranges under the pulsed 0-V to 10-V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched  $C_{\rm gd}$  model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

#### SUBCIRCUIT MODEL SCHEMATIC



This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.

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SPECIFICATIONS (T <sub>J</sub> = 25°C UNLESS OTHERWISE NOTED)					
Parameter	Symbol	Test Condition	Simulated Data	Measured Data	Unit
Static	-				•
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$ , $I_{D} = 250 \mu A$	3.5		V
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	V <sub>DS</sub> = 5 V, V <sub>GS</sub> = 10 V	662		Α
Drain-Source On-State Resistance <sup>a</sup>	Г <sub>DS(on)</sub>	$V_{GS}$ = 10 V, $I_{D}$ = 20 A	0.0064	0.0065	Ω
		$V_{GS}$ = 10 V, $I_{D}$ = 20 A, $T_{J}$ = 125°C	0.0096		
		V <sub>GS</sub> = 10 V, I <sub>D</sub> = 20 A, T <sub>J</sub> = 175°C	0.0114		
Forward Voltage <sup>a</sup>	V <sub>SD</sub>	I <sub>F</sub> = 50 A, V <sub>GS</sub> = 0 V	0.91	1	V
Dynamic <sup>b</sup>					
Input Capacitance	C <sub>iss</sub>	V <sub>GS</sub> = 0 V, V <sub>DS</sub> = 25 V, f = 1 MHz	6629	7000	pF
Output Capacitance	Coss		463	450	
Reverse Transfer Capacitance	$C_{rss}$		189	240	
Total Gate Charge <sup>c</sup>	Qg	$V_{DS} = 30 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 50 \text{ A}$	99	94	nC
Gate-Source Charge <sup>c</sup>	$Q_{gs}$		35	35	
Gate-Drain Charge <sup>c</sup>	$Q_{gd}$		20	20	

#### Notes

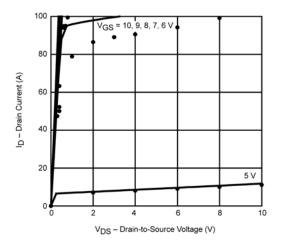
- a. Pulse test; pulse width  $\leq$  300  $\mu$ s, duty cycle  $\leq$  2%. b. Guaranteed by design, not subject to production testing. c. Independent of operating temperature.

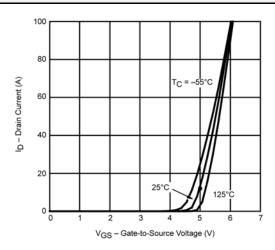


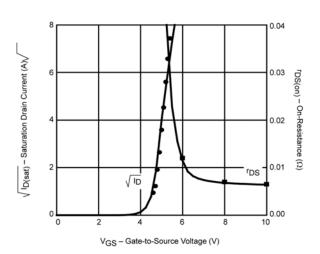
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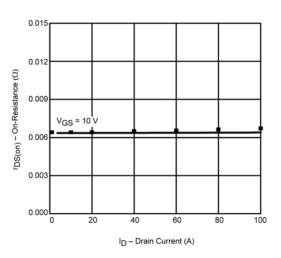
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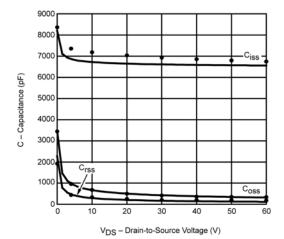
### COMPARISON OF MODEL WITH MEASURED DATA (TJ=25°C UNLESS OTHERWISE NOTED)

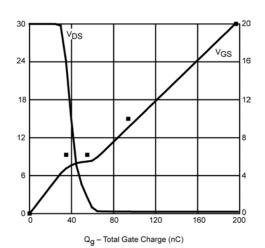












Note: Dots and squares represent measured data.



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